**Product data sheet** 

## 1. General description

Dual Silicon Carbide Schottky diode in a 3-lead TO247 plastic package, designed for high frequency switched-mode power supplies.





### 2. Features and benefits

- · Highly stable switching performance
- High forward surge capability I<sub>FSM</sub>
- · Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- · Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant
- High junction operating temperature capability (T<sub>j(max)</sub> = 175 °C)

# 3. Applications

- · Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter Parameter		Values			Unit				
Absolute	Absolute maximum rating									
$V_{RRM}$	repetitive peak reverse voltage 1200						V			
I <sub>O(AV)</sub>	limiting average output current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 147 °C; square-wave pulse; both diodes conducting; Fig. 1; Fig. 2; Fig. 3; Fig. 4	10		A					
T <sub>j</sub>	junction temperature		175			°C				
Symbol	Parameter	Conditions	Min Typ Max		Unit					
Static ch	aracteristics									
V <sub>F</sub>	forward voltage	$I_F = 5 \text{ A}$ ; $T_j = 25 \text{ °C}$ ; per diode; Fig. 6		-	1.4	1.6	V			
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 150 °C; per diode; <u>Fig. 6</u>		-	1.85	2.3	V			
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 175 °C; per diode; <u>Fig. 6</u>		-	2	2.6	V			
Dynamic characteristics										
Q <sub>r</sub>	recovered charge	$I_F = 5 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; per diode; Fig. 8$		-	12	-	nC			

# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode		
2	K	cathode		A1
3	A2	anode		K
mb	К	mounting base; connected to cathode		sym125

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC101200CW	TO247	WNSC101200CWQ	Tube	30	TO247N	20-Jul-2016

# 7. Marking

### Table 4. Marking codes

Type number	Marking codes
WNSC101200CW	WNSC101200CW

# 8. Limiting values

### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage		1200	V
$V_{\text{RWM}}$	crest working reverse voltage		1200	V
$V_R$	reverse voltage	DC	1200	V
I <sub>FRM</sub>	repetitive peak forward current	$δ = 0.5$ ; $t_p = 25 \mu s$ ; $T_{mb} \le 147 °C$ ; square-wave pulse; per diode	10	А
I <sub>O(AV)</sub>	limiting average output current	$\delta$ = 0.5 ; $T_{mb} \le$ 144 °C; square-wave pulse; both diodes conducting; Fig. 1; Fig. 2; Fig. 3; Fig. 4	10	А
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	65	А
		$t_p$ = 10 µs; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	525	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; per diode	21	A <sup>2</sup> s
T <sub>stg</sub>	storage temperature		-55 to 175	°C
T <sub>j</sub>	junction temperature		175	°C

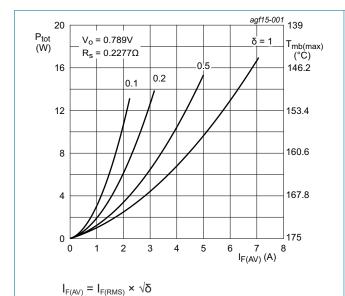


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; typical values; per diode

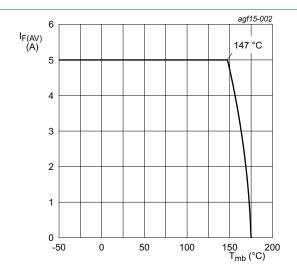
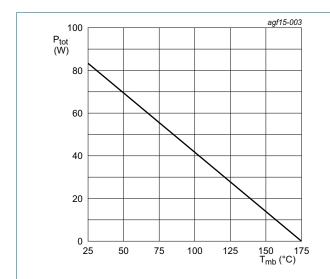


Fig. 2. Forward current as a function of mounting base temperature; typical values; per diode





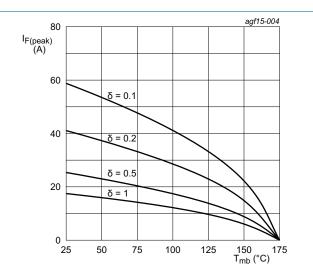


Fig. 4. Current derating as a function of mounting base temperature; per diode

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance	per diode; Fig. 5	-	-	1.8	K/W
	from junction to mounting base	both diodes conducting	-	-	1	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W

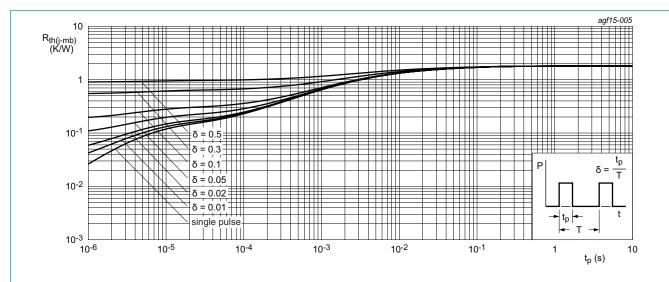
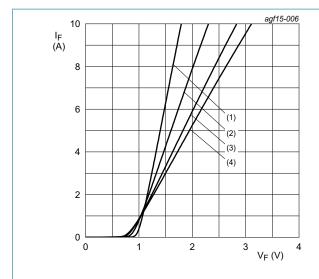


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
$V_{F}$	forward current	$I_F = 5 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$	-	1.4	1.6	V
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 150 °C; per diode; <u>Fig. 6</u>	-	1.85	2.3	V
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 175 °C; per diode; <u>Fig. 6</u>	-	2	2.6	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1200 V; T <sub>j</sub> = 25 °C; per diode; <u>Fig. 7</u>	-	4	50	μA
		V <sub>R</sub> = 1200 V; T <sub>j</sub> = 175 °C; per diode; <u>Fig. 7</u>	-	150	-	μA
Dynamic	characteristics					
Q <sub>r</sub>	recovered charge	$I_F = 5 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 500 \text{ A}/\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; per diode; Fig. 8	-	12	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C	-	250	-	pF
		f = 1 MHz; V <sub>R</sub> = 400 V; T <sub>j</sub> = 25 °C	-	24.5	-	pF
		f = 1 MHz; V <sub>R</sub> = 800 V; T <sub>j</sub> = 25 °C	-	22	-	pF



(1) T<sub>j</sub> = 25 °C; typical values (2) T<sub>j</sub> = 100 °C; typical values

(3) T<sub>i</sub> = 150 °C; typical values (4) T<sub>i</sub> = 175 °C; typical values

Fig. 6. Forward current as a function of forward voltage; typical values; per diode

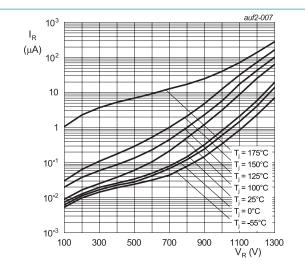
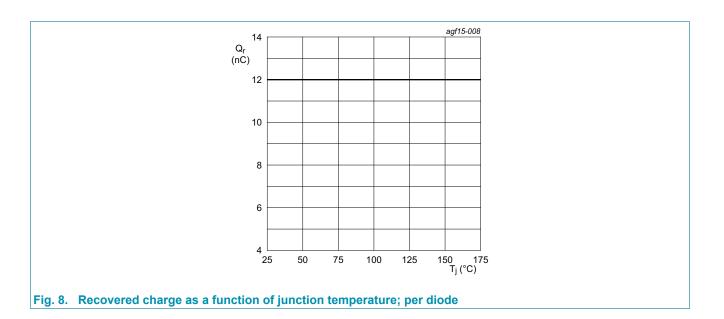
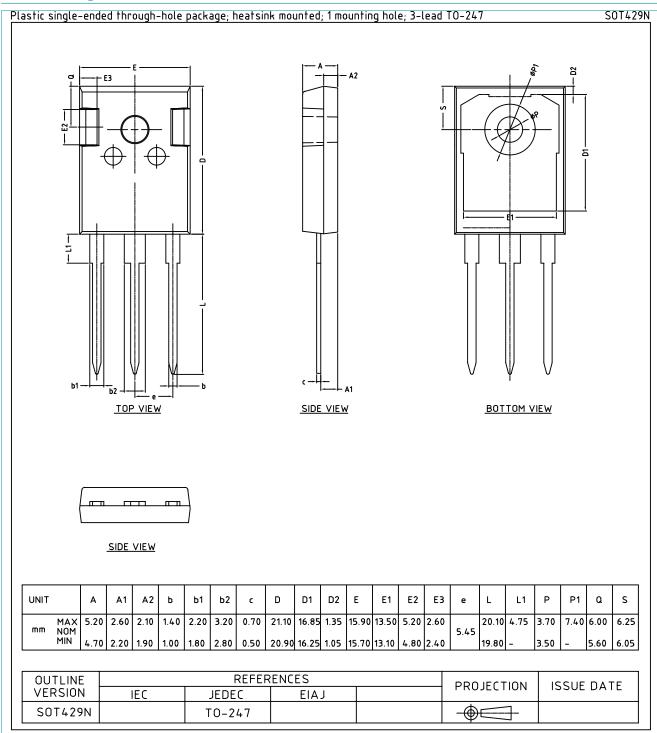


Fig. 7. Reverse leakage current as a function of reverse voltage; typical value; per diode



# 11. Package outline



## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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Date of release: 04 December 2019

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